



Shanghai Lunsure Electronic
Technology Co.,Ltd
Tel:0086-21-37185008
Fax:0086-21-57152769

RB490D THRU RB491D

Features

- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection

Mechanical Data

- Case :SOT-346,Molded Plastic
- Terminals :Solderable per MIL-STD-202,Method 208
- Polarity :See Diagrams Below
- Weight :0.008 grams (approx)
- Mountion Position :Any

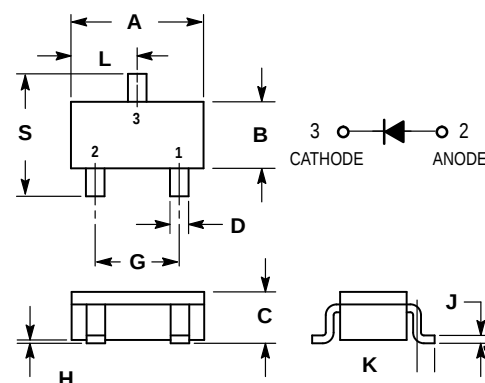
Maximum Ratings

- Operating Temperature: -25°C to +125°C
- Storage Temperature: -50°C to +125°C

Catalog Number	Device Marking	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
RB491D	10T	20V	14V	20V
RB490D	10F	40V	28V	40V

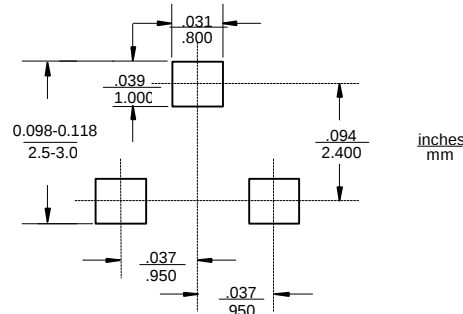
1Amp Surface Mount Schottky Barrier Diode 20 to 40 Volts

SOT-346



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.106	.122	2.70	3.10	
B	.051	.067	1.30	1.70	
C	.039	.051	1.00	1.30	
D	.014	.020	0.35	0.50	
E	.067	.091	1.70	2.30	
F	.000	.004	0.00	0.10	
G	.004	.010	0.10	0.26	
H	.008	.024	0.20	0.60	
I	.049	.065	1.25	1.65	
J	.089	.118	2.25	3.00	

Suggested Solder Pad Layout



Electrical Characteristics @ 25°C Unless Otherwise Specified

Average Forward Current	$I_{F(AV)}$	1.0A	$T_A = 90^\circ\text{C}$
Peak Forward Surge Current	I_{FSM}	5A	8.3ms, half sine
Maximum Forward Voltage Drop Per Element	V_F	0.45V 0.53V	$I_{FM} = 1.0A$ $T_J = 25^\circ\text{C}$
Maximum DC Reverse Current At Rated DC Blocking Voltage	I_R	100mA 4.0mA	$T_J = 25^\circ\text{C}$ $T_J = 100^\circ\text{C}$

*Pulse Test: Pulse Width 300μsec, Duty Cycle 1%

RB490D thru RB491D

RATING AND CHARACTERISTIC CURVES

FIG.1-TYPICAL FORWARD CHARACTERISTICS

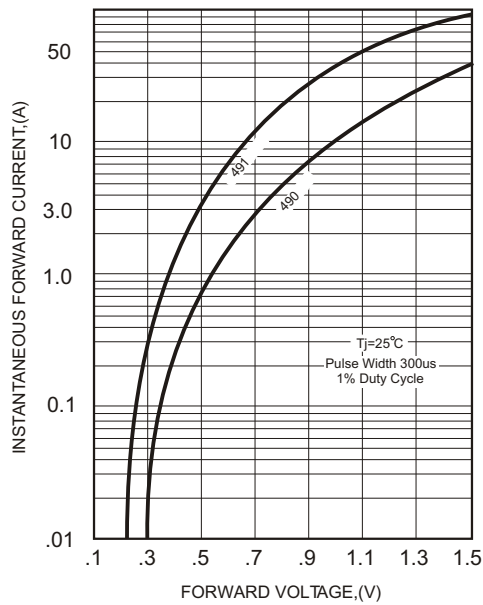


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

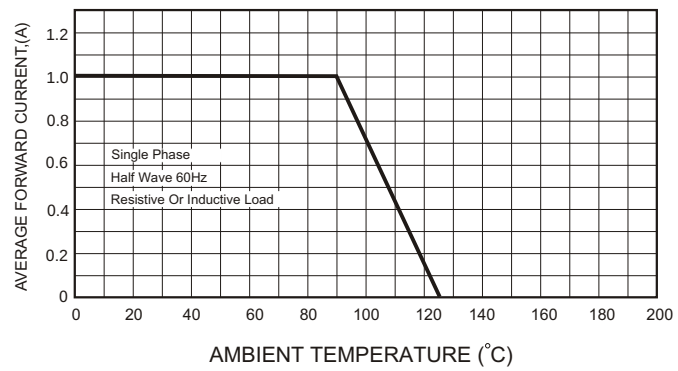


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

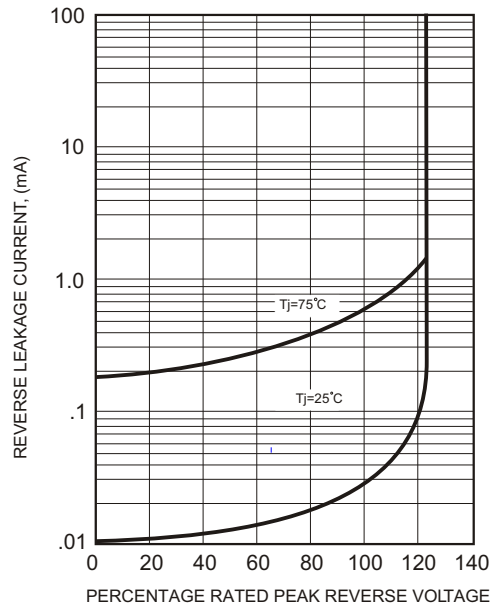


FIG.4-TYPICAL JUNCTION CAPACITANCE

